

DATA SHEET

BYV42E, BYV42EB series
Rectifier diodes
ultrafast, rugged

Product specification

July 1998



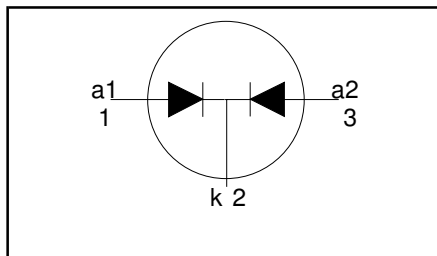
Rectifier diodes ultrafast, rugged

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FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

| |
|---------------------------------------|
| $V_R = 150 \text{ V} / 200 \text{ V}$ |
| $V_F \leq 0.85 \text{ V}$ |
| $I_{O(AV)} = 30 \text{ A}$ |
| $I_{RRM} = 0.2 \text{ A}$ |
| $t_r \leq 28 \text{ ns}$ |

GENERAL DESCRIPTION

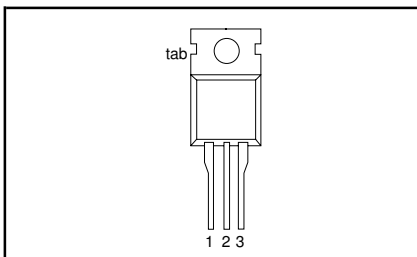
Dual, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV42E series is supplied in the SOT78 conventional leaded package.
The BYV42EB series is supplied in the SOT404 surface mounting package.

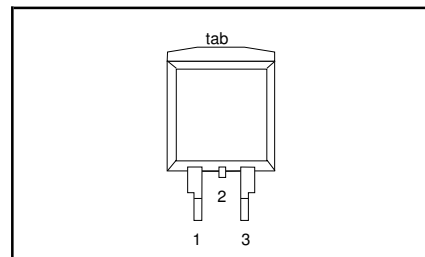
PINNING

| PIN | DESCRIPTION |
|-----|--------------------------|
| 1 | anode 1 (a) |
| 2 | cathode (k) ¹ |
| 3 | anode 2 (a) |
| tab | cathode (k) |

SOT78 (TO220AB)



SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|-------------|---|--|------|------------------|------|------------------|
| | | | | BYV42E / BYV42EB | | |
| V_{RRM} | Peak repetitive reverse voltage | $T_{mb} \leq 144^\circ\text{C}$ | - | -150 | -200 | V |
| V_{RWM} | Crest working reverse voltage | | - | 150 | 200 | V |
| V_R | Continuous reverse voltage | | - | 150 | 200 | V |
| $I_{O(AV)}$ | Average rectified output current (both diodes conducting) | square wave | - | 30 | | A |
| I_{FRM} | Repetitive peak forward current per diode | $\delta = 0.5; T_{mb} \leq 108^\circ\text{C}$ $t = 25 \mu\text{s}; \delta = 0.5;$ | - | 30 | | A |
| I_{FSM} | Non-repetitive peak forward current per diode | $T_{mb} \leq 108^\circ\text{C}$ $t = 10 \text{ ms}$ | - | 150 | | A |
| | | $t = 8.3 \text{ ms}$ sinusoidal; with reapplied | - | 160 | | A |
| I_{RRM} | Repetitive peak reverse current per diode | $V_{RWM(max)}$ $t_p = 2 \mu\text{s}; \delta = 0.001$ | - | 0.2 | | A |
| I_{RSM} | Non-repetitive peak reverse current per diode | $t_p = 100 \mu\text{s}$ | - | 0.2 | | A |
| T_{stg} | Storage temperature | | -40 | 150 | | $^\circ\text{C}$ |
| T_j | Operating junction temperature | | - | 150 | | $^\circ\text{C}$ |

1. It is not possible to make connection to pin 2 of the SOT404 package

2. SOT78 package, For output currents in excess of 20 A, the cathode connection should be made to the mounting tab.

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ESD LIMITING VALUE

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------|---|---|------|------|------|
| V_C | Electrostatic discharge capacitor voltage | Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$ | - | 8 | kV |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|--|---|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance junction to mounting base | per diode | - | - | 2.4 | K/W |
| | | both diodes | - | - | 1.4 | K/W |
| $R_{th\ j-a}$ | Thermal resistance junction to ambient | SOT78 package, in free air | - | 60 | - | K/W |
| | | SOT404 and SOT428 packages, pcb mounted, minimum footprint, FR4 board | - | 50 | - | K/W |

ELECTRICAL CHARACTERISTICS

characteristics are per diode at $T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------|--------------------------|---|------|------|------|---------------|
| V_F | Forward voltage | $I_F = 15 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$ | - | 0.78 | 0.85 | V |
| | | $I_F = 15 \text{ A}$ | - | 0.95 | 1.05 | V |
| | | $I_F = 30 \text{ A}$ | - | 1.00 | 1.20 | V |
| I_R | Reverse current | $V_R = V_{RWM}$; $T_j = 100 \text{ }^\circ\text{C}$ | - | 0.5 | 1 | mA |
| | | $V_R = V_{RWM}$ | - | 10 | 100 | μA |
| Q_s | Reverse recovery charge | $I_F = 2 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 20 \text{ A}/\mu\text{s}$ | - | 6 | 15 | nC |
| t_{rr1} | Reverse recovery time | $I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ | - | 20 | 28 | ns |
| t_{rr2} | Reverse recovery time | $I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; $I_{rec} = 0.25 \text{ A}$ | - | 13 | 22 | ns |
| V_{fr} | Forward recovery voltage | $I_F = 1 \text{ A}$; $di_F/dt = 10 \text{ A}/\mu\text{s}$ | - | 1 | - | V |

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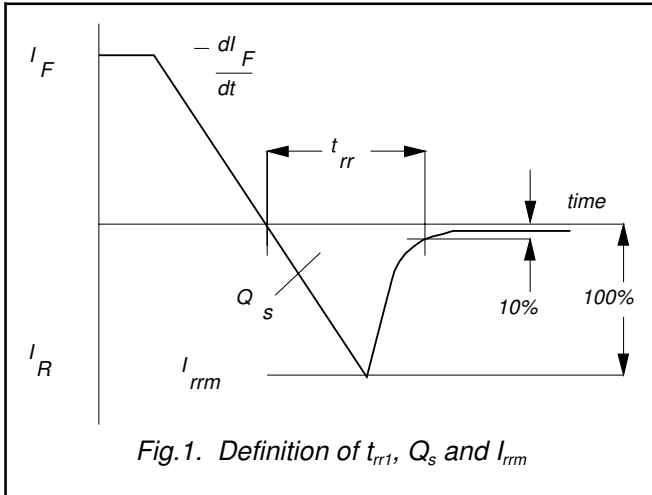


Fig.1. Definition of t_{rr1} , Q_s and I_{rm}

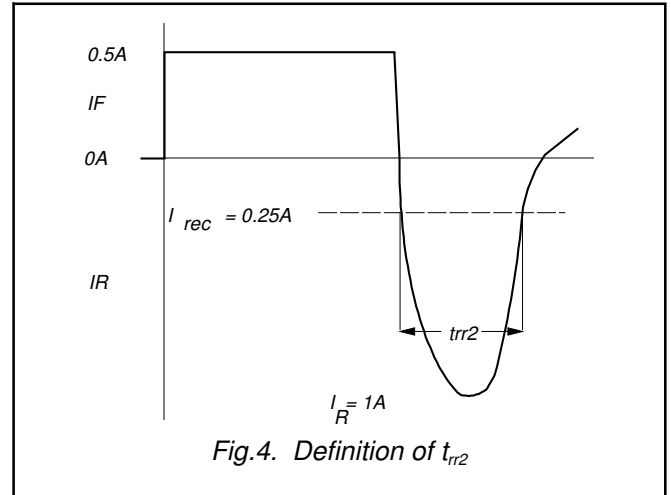


Fig.4. Definition of t_{rr2}

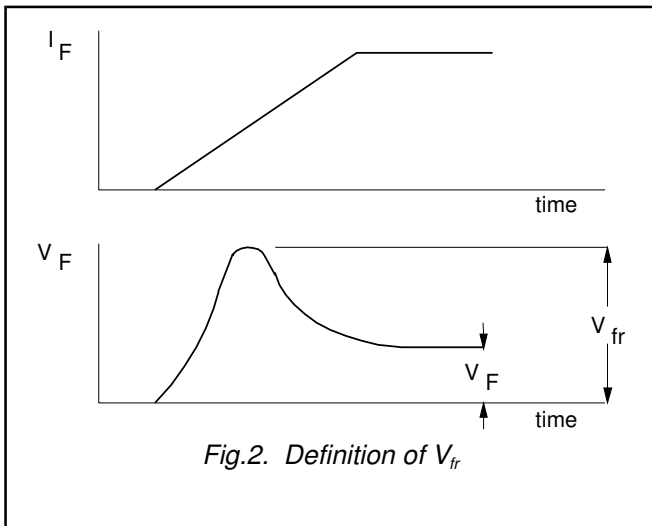


Fig.2. Definition of V_{fr}

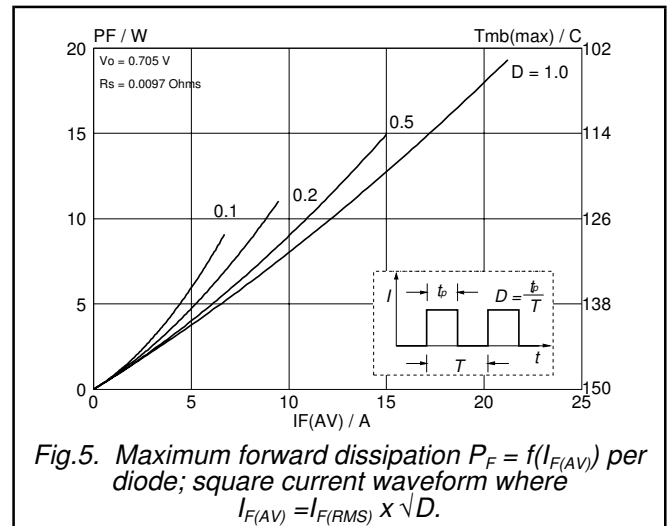


Fig.5. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

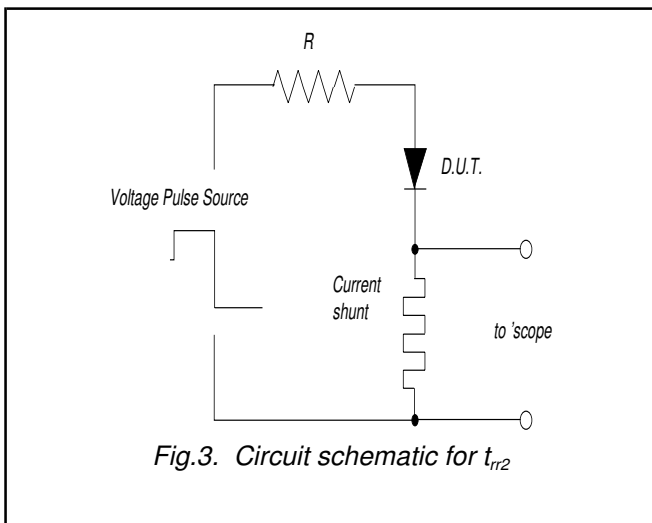


Fig.3. Circuit schematic for t_{rr2}

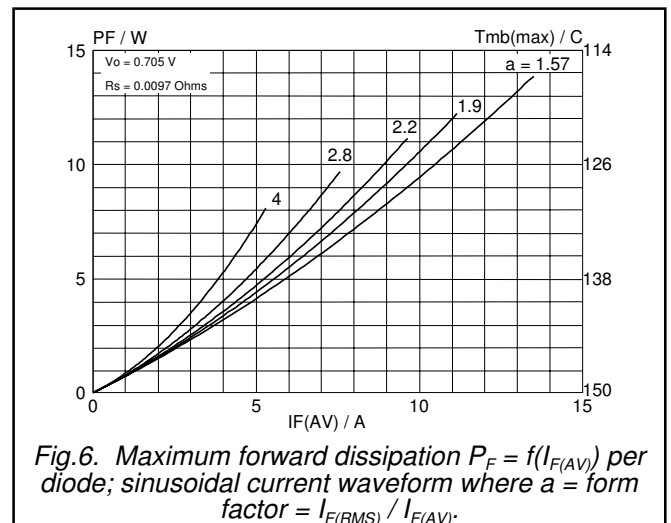
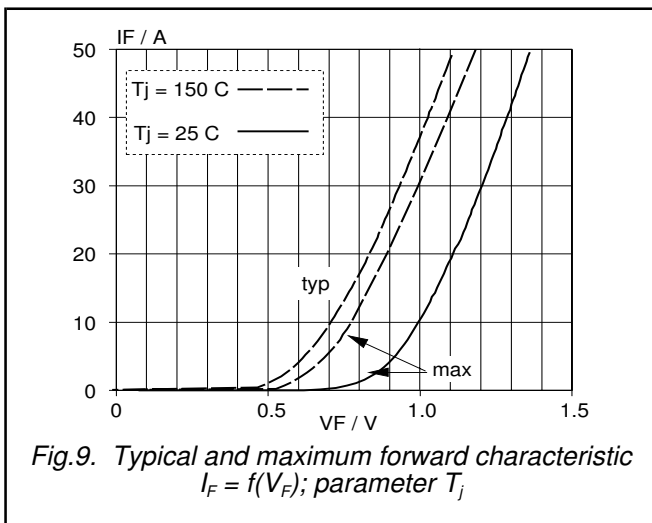
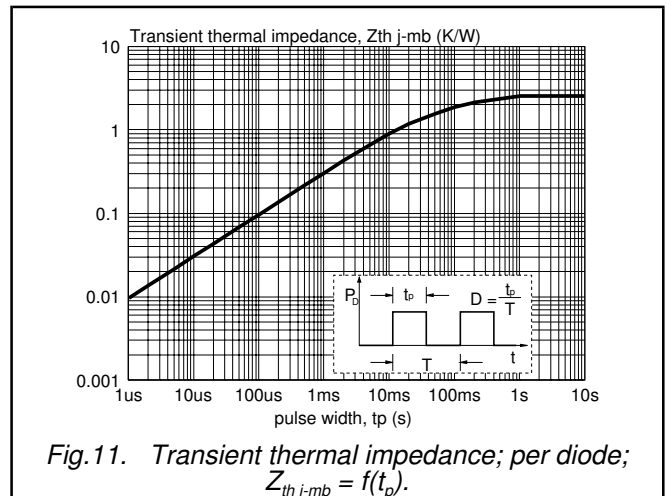
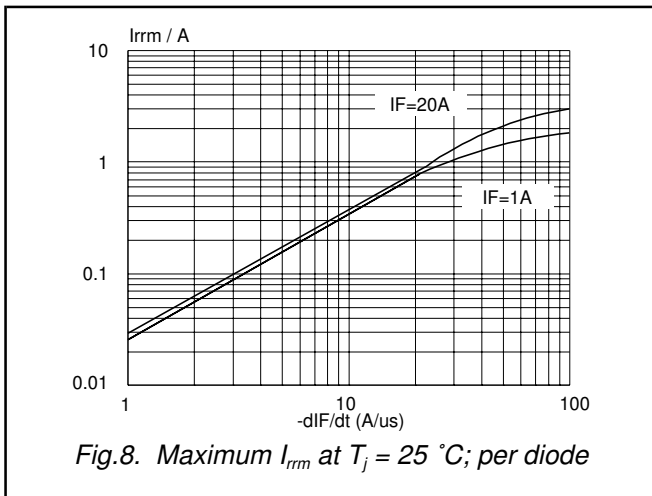
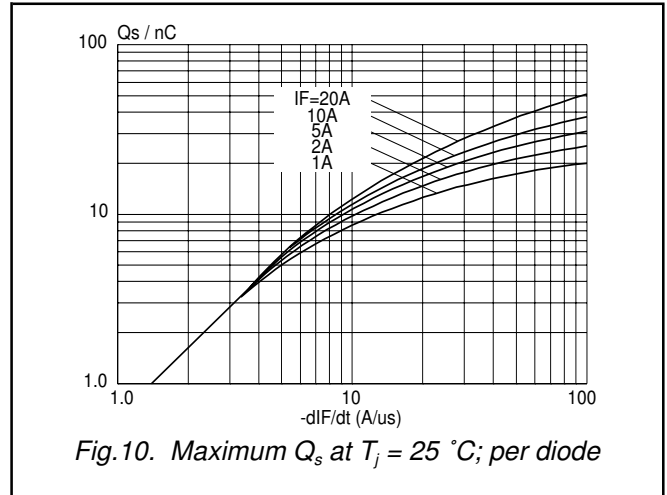
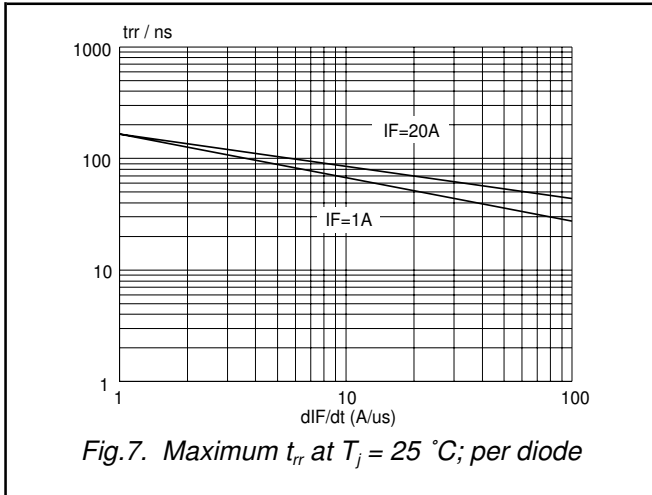


Fig.6. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; sinusoidal current waveform where $a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$.

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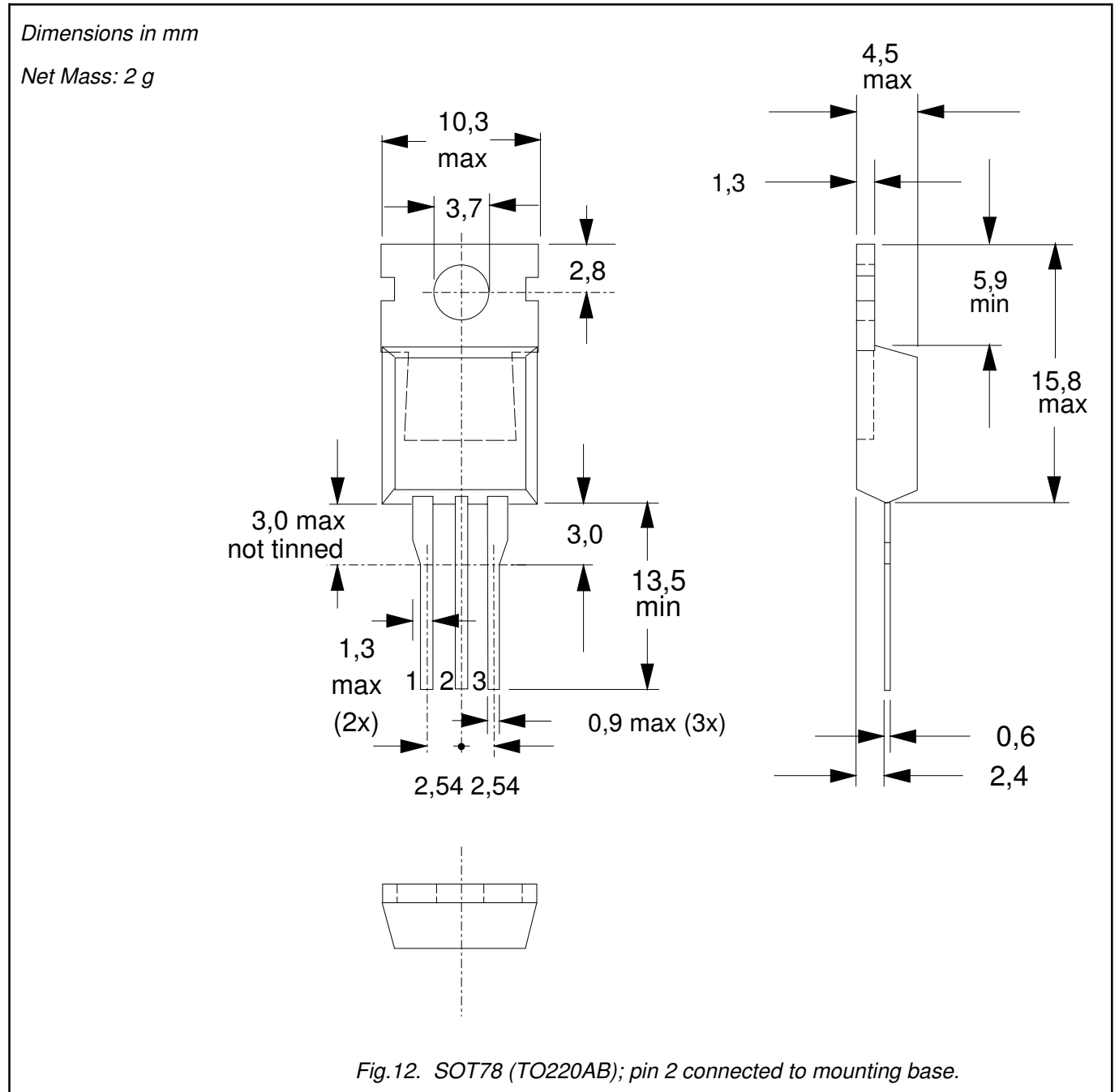
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MECHANICAL DATA



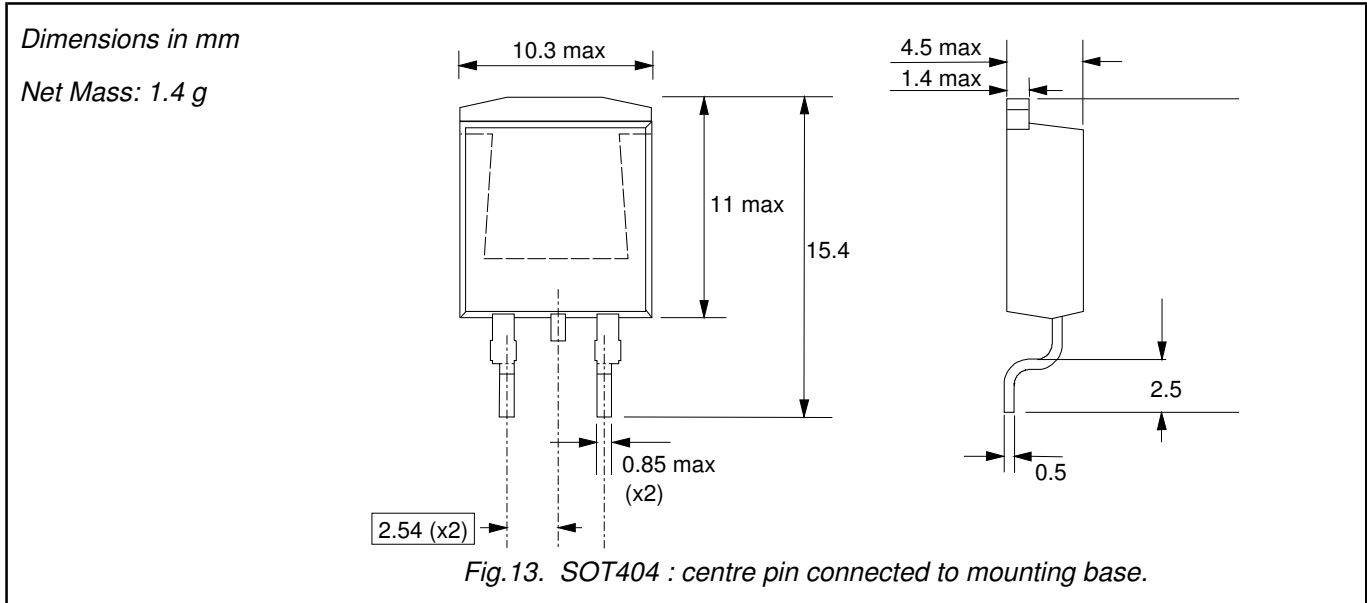
Notes

1. Refer to mounting instructions for SOT78 (TO220) envelopes.
2. Epoxy meets UL94 V0 at 1/8".

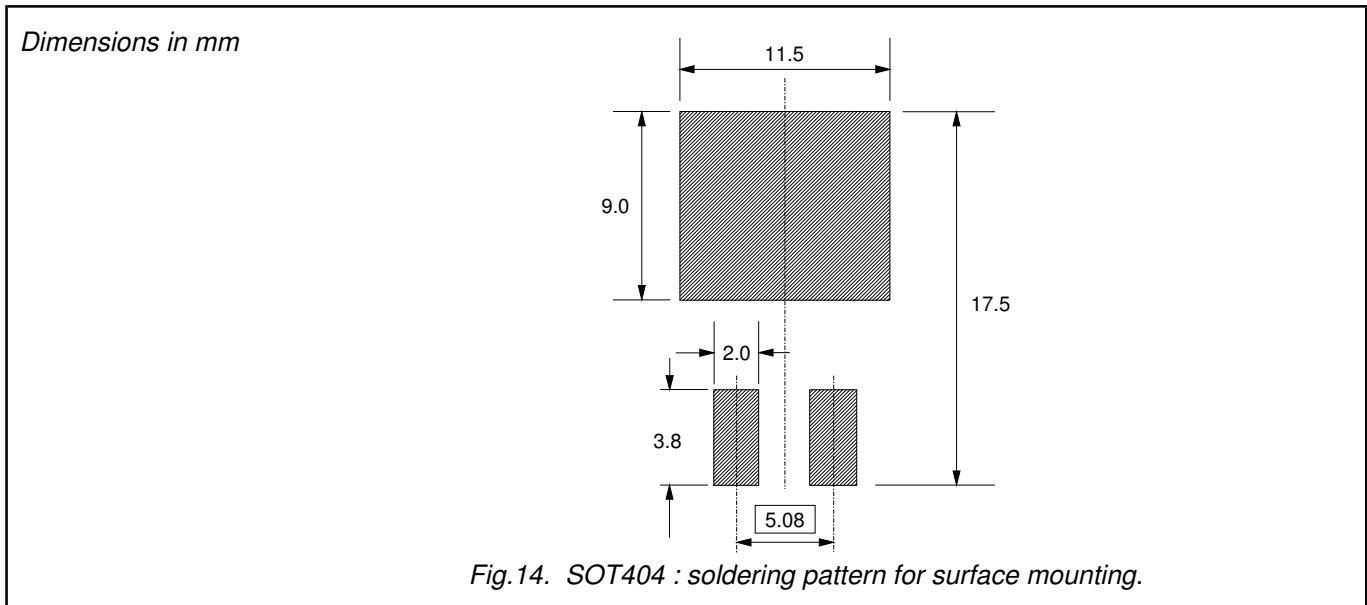
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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

- 1. Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|--------------------------------|-------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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